

13 FEB. 2003

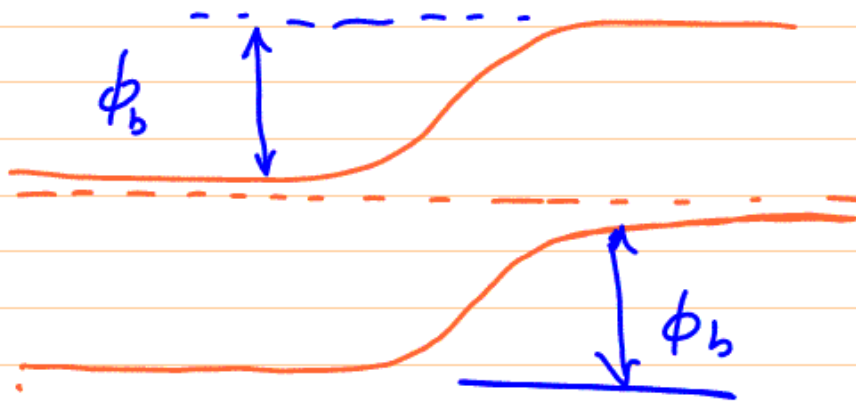
Note Title

2/10/2003

HETEROJUNCTION CURRENTS

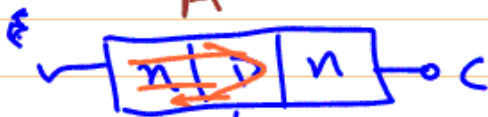
a) NORMAL TO JUNCTION

IN HOMOJUNCTION HOLES AND ELECTRONS SEE THE SAME POTENTIAL BARRIER,



WE FIND $i_0 = \underline{I_s} (e^{2V_{ns}/kT} - 1)$

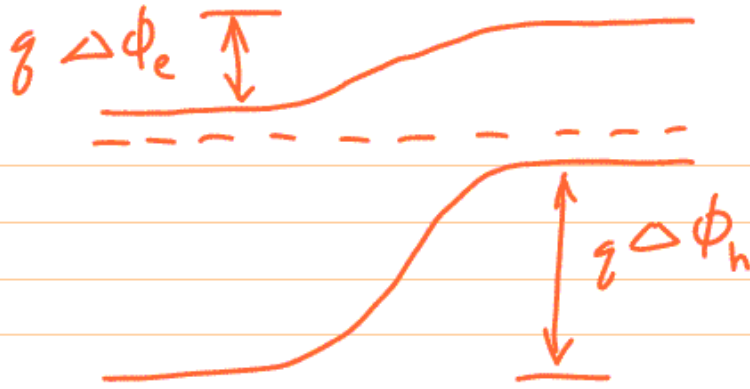
$$\frac{I_s}{A} = q n_i^2 \left(\underbrace{\frac{D_e}{W_p N_{Ap}}}_{\text{electrons}} + \underbrace{\frac{D_h}{W_n N_{Dn}}}_{\text{holes}} \right)$$



THUS $\frac{i_{\text{ELECTRON}}}{i_{\text{HOLE}}} = \frac{D_e}{D_h} \times \frac{W_n}{W_p} \times \frac{N_{Dn}}{N_{Ap}} = \eta_{en}$

2-3 ≈ 1 =

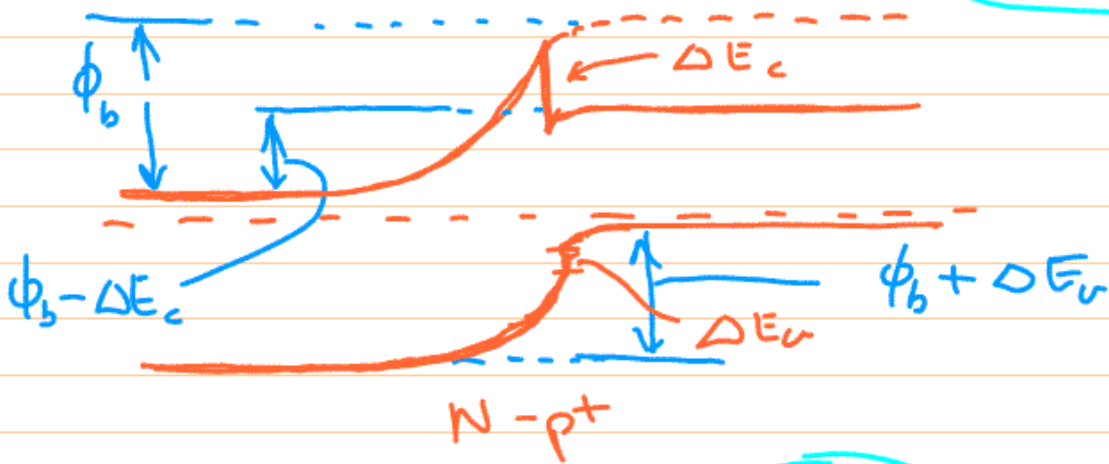
TO MAKE $i_e \gg i_h$, MAKE $\underline{N_{Dn}} \gg \underline{N_{Ap}}$



$$\frac{i_{ELECT}}{i_{HOLE}} = \frac{D_e}{D_h} \times \frac{W_n}{W_p} \times \frac{N_{Dn}}{N_{Ap}} \times e^{\frac{g}{kT} (\Delta\phi_h - \Delta\phi_e)}$$

* Now we can have $i_e > i_h$ EVEN IF $N_{Ap} > N_{Dn}$

IMPACT OF SPIKE



BARRIERS:

ELECTRONS SEE:

W.O. SPIKE

W. SPIKE

$\phi_b - \Delta E_c$

$\sim \phi_b$

HOLES SEE:

$\phi_b + \Delta E_v$

$\phi_b + \Delta E_v$

DIFFERENCE

ΔE_g

ΔE_v

AN ASIDE — a useful observation

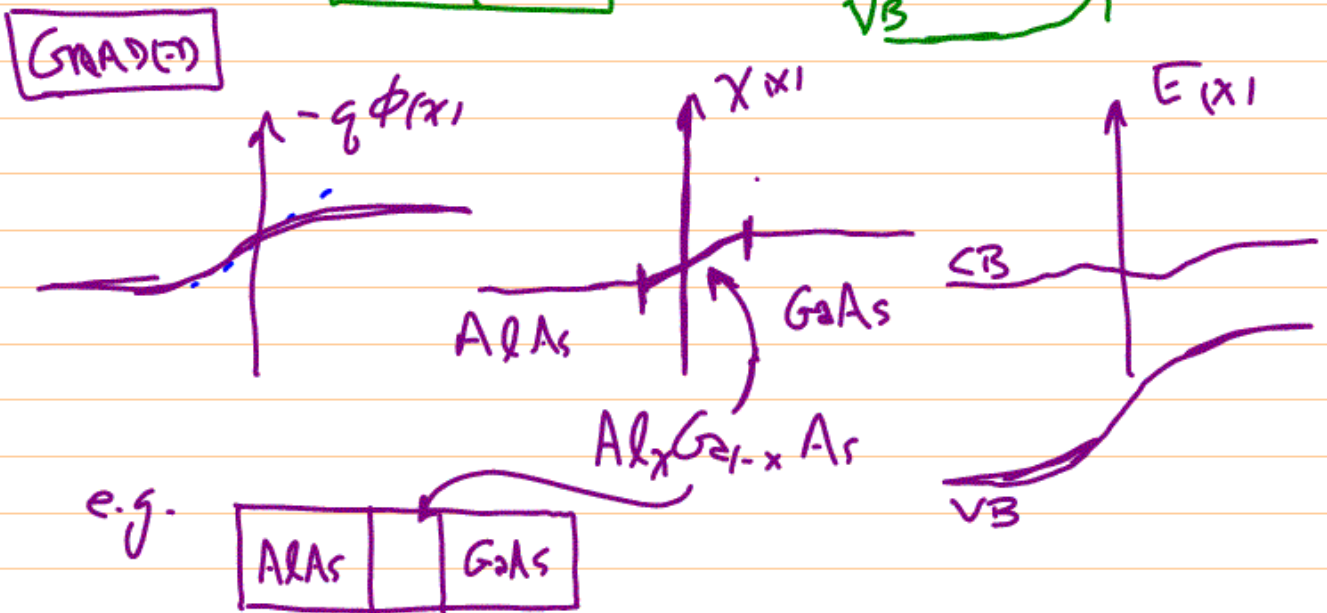
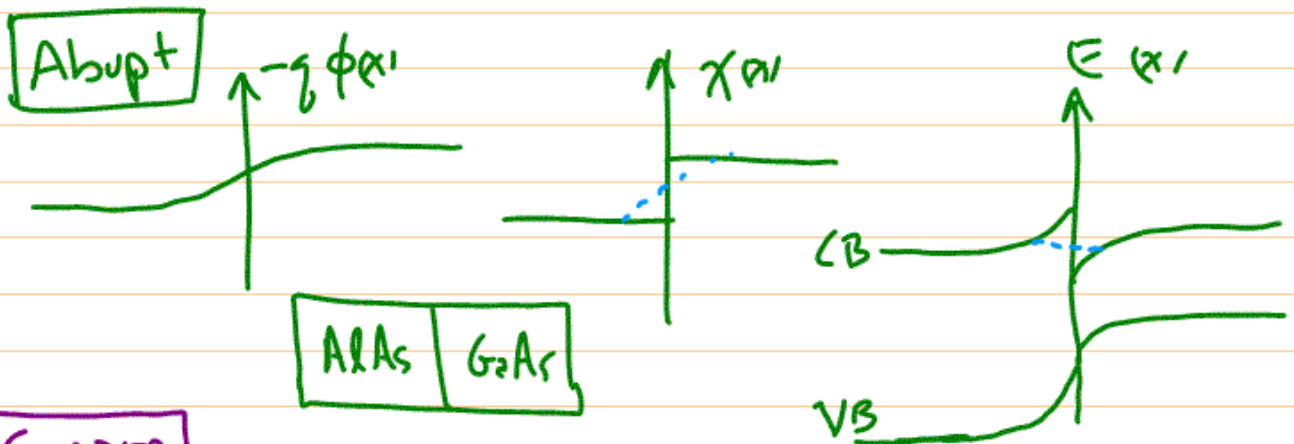
60mV RULE

AT R.T. $e^{q(0.06/kT)} \approx 10$

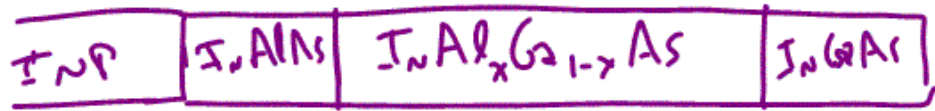
AND $e^{q n (0.06)/kT} \approx 10^n$

ELIMINATING A SPIKE

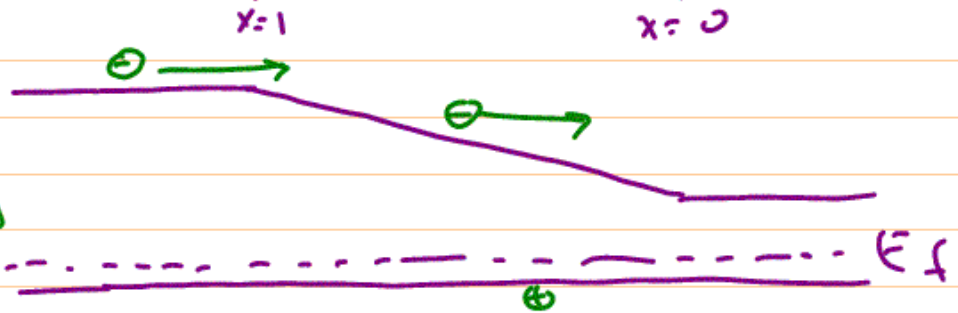
RECALL: $E_c(x) = -q\phi(x) - \chi(x)$



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EFFECTIVE FIELD DUE TO COMPOSITION GRADING



IN THERMAL EQUILIB.

$$n_0(x) = N_c e^{-(E_c - E_f) / kT}$$

↑ FERMIL LEVEL

$$p_0(x) = N_v e^{-(E_f - E_v) / kT}$$

* WE USE THE SAME RELATION TO DEFINE QFL'S WHEN NOT IN T.E.

$$n(x) = N_c e^{-(E_c - E_{fn}) / kT}$$

$$p(x) = N_v e^{-(E_{fp} - E_v) / kT}$$

QFL for electrons

Quasi Fermi level for holes

QUASI-FERMI LEVELS

$$E_{fn}(x) \equiv E_c(x) + kT \ln [n(x) / N_c(x)]$$

$-q\phi(x) - \chi(x)$

$$E_{fp}(x) \equiv E_v(x) - kT \ln [p(x) / N_v(x)]$$

$-q\phi(x) - [\chi(x) + E_g(x)]$

USE IN:

$$J_e = n \mu_e \frac{dE_{fn}}{dx}$$

$$J_h = p \mu_h \frac{dE_{fp}}{dx}$$

FIND FOR ELECTRONS

$$J_e = -q n \mu_e \frac{\partial \phi}{\partial x} - n \mu_e \frac{\partial \chi}{\partial x} + q D_e \frac{\partial n}{\partial x}$$

$$q n \mu_e E_x$$

DRIFT

New factor

DIFFUSION

$$-q D_e \frac{n}{N_c} \frac{\partial A_c}{\partial x}$$

New also but small
 \therefore neglect

FOR HOLES WE FIND SIMILARLY:

$$J_h \approx \text{DRIFT} + \text{DIFFUSION} - p \mu_h \frac{\partial (\chi + \phi_s)}{\partial x}$$

(" \approx " BECAUSE WE NEGLECT $\partial N_v / \partial x$)

WE CAN THINK OF $\partial \chi / \partial x$ AND $\partial (\chi + \phi_s) / \partial x$ AS "EFFECTIVE" ELECTRIC FIELDS THAT ADD TO THE DRIFT ALONG WITH OUR "TRADITIONAL" ELECTRIC FIELD, $-q \partial \phi / \partial x$. CLEARLY THE EFFECTIVE FIELD IS DIFFERENT FOR HOLES AND ELECTRONS.